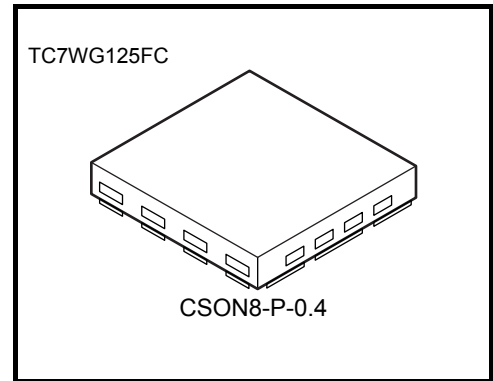


# TC7WG125FC

## Dual Bus Buffer with 3-STATE Output

### Features

- High-level output current:  $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$   
at  $V_{CC} = 3 \text{ V}$
- High-speed operation:  $t_{pd} = 2.5 \text{ ns (typ.)}$   
at  $V_{CC} = 3.3 \text{ V}, 15\text{pF}$
- Operating voltage range:  $V_{CC} = 0.9\sim 3.6 \text{ V}$
- 5.5-V tolerant inputs
- 3.6-V power down protection outputs



Weight: 0.002 g (typ.)

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	$V_{CC}$	-0.5~4.6	V
DC input voltage	$V_{IN}$	-0.5~7.0	V
DC output voltage	$V_{OUT}$	-0.5~4.6 (Note 1)	V
		-0.5~ $V_{CC} + 0.5$ (Note 2)	
Input diode current	$I_{IK}$	-20	mA
Output diode current	$I_{OK}$	-20 (Note 3)	mA
DC output current	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}/GND$ current	$I_{CC}$	$\pm 100$	mA
Power dissipation	$P_D$	150 (Note 4)	mW
Storage temperature	$T_{stg}$	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0 \text{ V}$

Note 2: High or Low State.

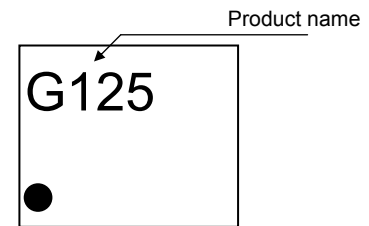
$I_{OUT}$  absolute maximum rating must be observed.

Note 3:  $V_{OUT} < GND$

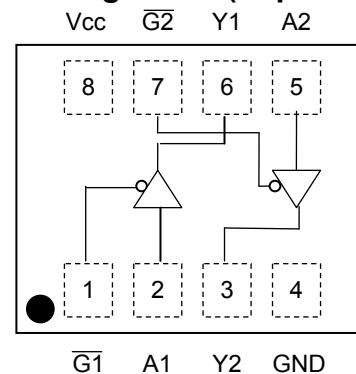
Note 4: Mounted on an FR4 board.

(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 11.56 mm<sup>2</sup>)

### Marking



### Pin Assignment ( top view )

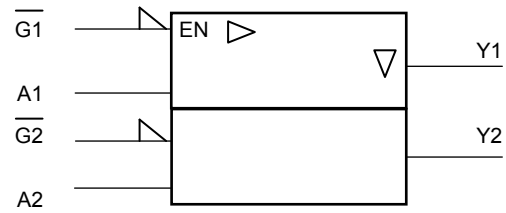


### Truth Table

Inputs		Outputs
$\overline{G}$	A	Y
H	X	Z
L	L	L
L	H	H

X: Don't Care  
Z: High impedance

### IEC Logic Symbol



### Operating Ranges

Characteristics	Symbol	Value	Unit
Power supply voltage	$V_{CC}$	0.9~3.6	V
Input voltage	$V_{IN}$	0~5.5	V
Output voltage	$V_{OUT}$	0~3.6 (Note 5)	V
		0~ $V_{CC}$ (Note 6)	
Output Current	$I_{OH}/I_{OL}$	$\pm 8.0$ (Note 7)	mA
		$\pm 4.0$ (Note 8)	
		$\pm 3.0$ (Note 9)	
		$\pm 1.7$ (Note 10)	
		$\pm 0.3$ (Note 11)	
		$\pm 0.02$ (Note 12)	
Operating temperature	$T_{opr}$	-40~85	$^{\circ}C$
Input rise and fall time	$dt/dV$	0~10 (Note 13)	ns/V

Note 5:  $V_{CC} = 0$  V

Note 6: High or Low state.

Note 7:  $V_{CC} = 3.0\sim 3.6$  V

Note 8:  $V_{CC} = 2.3\sim 2.7$  V

Note 9:  $V_{CC} = 1.65\sim 1.95$  V

Note 10:  $V_{CC} = 1.4\sim 1.6$  V

Note 11:  $V_{CC} = 1.1\sim 1.3$  V

Note 12:  $V_{CC} = 0.9$  V

Note 13:  $V_{IN} = 0.8\sim 2.0$  V,  $V_{CC} = 3.0$  V

## Electrical Characteristics

### DC Characteristics

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit			
			V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max		
Input voltage	High level	V <sub>IH</sub>	—	0.9	V <sub>CC</sub>	—	—	V <sub>CC</sub>	—	V	
				1.1~1.3	V <sub>CC</sub> × 0.7	—	—	V <sub>CC</sub> × 0.7	—		
				1.4~1.6	V <sub>CC</sub> × 0.65	—	—	V <sub>CC</sub> × 0.65	—		
				1.65~1.95	V <sub>CC</sub> × 0.65	—	—	V <sub>CC</sub> × 0.65	—		
				2.3~2.7	1.7	—	—	1.7	—		
				3.0~3.6	2.0	—	—	2.0	—		
	Low level	V <sub>IL</sub>	—	0.9	—	—	GND	—	GND		
				1.1~1.3	—	—	V <sub>CC</sub> × 0.3	—	V <sub>CC</sub> × 0.3		
				1.4~1.6	—	—	V <sub>CC</sub> × 0.35	—	V <sub>CC</sub> × 0.35		
				1.65~1.95	—	—	V <sub>CC</sub> × 0.35	—	V <sub>CC</sub> × 0.35		
				2.3~2.7	—	—	0.7	—	0.7		
				3.0~3.6	—	—	0.8	—	0.8		
Output voltage	High level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>	I <sub>OH</sub> = -0.02 mA	0.9	0.75	—	—	0.75	—	V
				I <sub>OH</sub> = -0.3 mA	1.1~1.3	V <sub>CC</sub> × 0.75	—	—	V <sub>CC</sub> × 0.75	—	
				I <sub>OH</sub> = -1.7 mA	1.4~1.6	V <sub>CC</sub> × 0.75	—	—	V <sub>CC</sub> × 0.75	—	
				I <sub>OH</sub> = -3.0 mA	1.65~1.95	V <sub>CC</sub> - 0.45	—	—	V <sub>CC</sub> - 0.45	—	
				I <sub>OH</sub> = -4.0 mA	2.3~2.7	2.0	—	—	2.0	—	
				I <sub>OH</sub> = -8.0 mA	3.0~3.6	2.48	—	—	2.48	—	
	Low level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 0.02 mA	0.9	—	—	0.1	—	0.1	
				I <sub>OL</sub> = 0.3 mA	1.1~1.3	—	—	V <sub>CC</sub> × 0.25	—	V <sub>CC</sub> × 0.25	
				I <sub>OL</sub> = 1.7 mA	1.4~1.6	—	—	V <sub>CC</sub> × 0.25	—	V <sub>CC</sub> × 0.25	
				I <sub>OL</sub> = 3.0 mA	1.65~1.95	—	—	0.45	—	0.45	
				I <sub>OL</sub> = 4.0 mA	2.3~2.7	—	—	0.4	—	0.4	
				I <sub>OL</sub> = 8.0 mA	3.0~3.6	—	—	0.4	—	0.4	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5V	0~3.6	—	—	±0.1	—	±1.0	μA		
3-state output off-state current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0~3.6V	0.9~3.6	—	—	1.0	—	10.0	μA		
Power off leakage current	I <sub>OFF</sub>	V <sub>IN</sub> = 5.5V or V <sub>OUT</sub> = 3.6V	0.0	—	—	1.0	—	10.0	μA		
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	3.6	—	—	1.0	—	10.0	μA		

**AC Characteristics (Input:  $t_r = t_f = 3 \text{ ns}$ )**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40~85°C		Unit		
				Min	Typ.	Max	Min	Max			
Propagation delay time	t <sub>pLH</sub> t <sub>pHL</sub>	C <sub>L</sub> = 10 pF, R <sub>L</sub> = 1 MΩ	0.9	—	18.3	—	—	—	ns		
			1.1~1.3	—	9.4	18.4	1.0	34.9			
			1.4~1.6	—	5.5	8.5	1.0	10.7			
			1.65~1.95	—	4.2	6.2	1.0	6.7			
			2.3~2.7	—	2.8	3.9	1.0	4.4			
			3.0~3.6	—	2.3	3.1	1.0	3.7			
		C <sub>L</sub> = 15 pF, R <sub>L</sub> = 1 MΩ	0.9	—	21.2	—	—	—			
			1.1~1.3	—	10.7	21.5	1.0	38.0			
			1.4~1.6	—	6.1	9.3	1.0	11.9			
			1.65~1.95	—	4.7	6.9	1.0	7.1			
			2.3~2.7	—	3.1	4.4	1.0	5.0			
			3.0~3.6	—	2.5	3.4	1.0	3.9			
		C <sub>L</sub> = 30 pF, R <sub>L</sub> = 1 MΩ	0.9	—	30.5	—	—	—			
			1.1~1.3	—	14.9	30.0	1.0	58.1			
			1.4~1.6	—	8.2	13.2	1.0	16.6			
			1.65~1.95	—	6.1	9.2	1.0	9.9			
			2.3~2.7	—	4.1	5.7	1.0	6.1			
			3.0~3.6	—	3.4	4.4	1.0	4.8			
	Output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	C <sub>L</sub> = 10 pF, R <sub>L</sub> = 100 kΩ	0.9	—	24.0	—	—		—	ns
				C <sub>L</sub> = 10 pF, R <sub>L</sub> = 5 kΩ	1.1~1.3	—	11.8	22.5		1.0	
			1.4~1.6		—	6.8	10.4	1.0		12.0	
1.65~1.95			—		5.1	7.3	1.0	8.1			
2.3~2.7			—		3.4	4.6	1.0	5.3			
3.0~3.6			—		2.5	3.4	1.0	3.9			
C <sub>L</sub> = 15 pF, R <sub>L</sub> = 100 kΩ			0.9	—	26.6	—	—	—			
			C <sub>L</sub> = 15 pF, R <sub>L</sub> = 5 kΩ	1.1~1.3	—	13.0	25.0	1.0	41.9		
1.4~1.6				—	7.4	11.4	1.0	13.4			
1.65~1.95				—	5.5	7.9	1.0	8.5			
2.3~2.7				—	3.7	4.9	1.0	5.5			
3.0~3.6				—	3.0	4.1	1.0	4.6			
C <sub>L</sub> = 30 pF, R <sub>L</sub> = 100 kΩ			0.9	—	36.4	—	—	—			
			C <sub>L</sub> = 30 pF, R <sub>L</sub> = 5 kΩ	1.1~1.3	—	17.9	35.8	1.0	59.1		
1.4~1.6				—	9.8	15.3	1.0	17.8			
1.65~1.95				—	7.2	10.5	1.0	11.2			
2.3~2.7				—	4.5	5.9	1.0	6.6			
3.0~3.6				—	3.6	4.6	1.0	5.3			

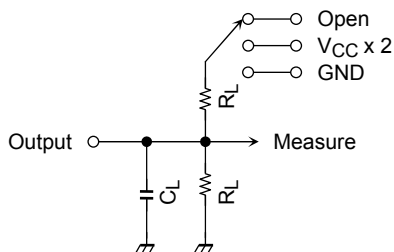
Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit	
			VCC (V)	Min	Typ.	Max	Min		Max
Output disable time	tpLZ tpHZ	CL = 10 pF, RL = 100 kΩ	0.9	—	168.6	—	—	ns	
		CL = 10 pF, RL = 5 kΩ	1.1~1.3	—	9.5	18.4	1.0		25.2
			1.4~1.6	—	7.5	9.5	1.0		10.6
			1.65~1.95	—	7.1	8.7	1.0		9.6
			2.3~2.7	—	6.8	7.9	1.0		8.8
			3.0~3.6	—	6.5	7.5	1.0		8.4
		CL = 15 pF, RL = 100 kΩ	0.9	—	201.8	—	—		—
		CL = 15 pF, RL = 5 kΩ	1.1~1.3	—	10.5	19.8	1.0		27.6
			1.4~1.6	—	9.0	10.4	1.0		12.3
			1.65~1.95	—	8.5	9.7	1.0		10.6
			2.3~2.7	—	7.9	8.8	1.0		10.3
			3.0~3.6	—	7.6	8.3	1.0		9.5
		CL = 30 pF, RL = 100 kΩ	0.9	—	251.5	—	—		—
		CL = 30 pF, RL = 5 kΩ	1.1~1.3	—	14.1	23.8	1.0		31.9
			1.4~1.6	—	13.5	14.5	1.0		16.0
			1.65~1.95	—	12.7	14.3	1.0		15.0
2.3~2.7	—		12.2	14.1	1.0	14.7			
3.0~3.6	—		11.9	13.8	1.0	14.4			
Input capacitance	CIN	—	3.6	—	3	—	—	pF	
Power dissipation capacitance	CPD	(Note 14)	0.9 ~ 3.6	—	10	—	—	—	pF

Note 14: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC} (opr.) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$$

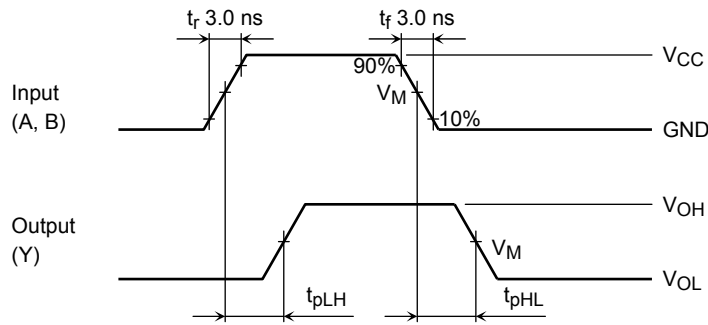
**AC Characteristics Measurement Circuit**



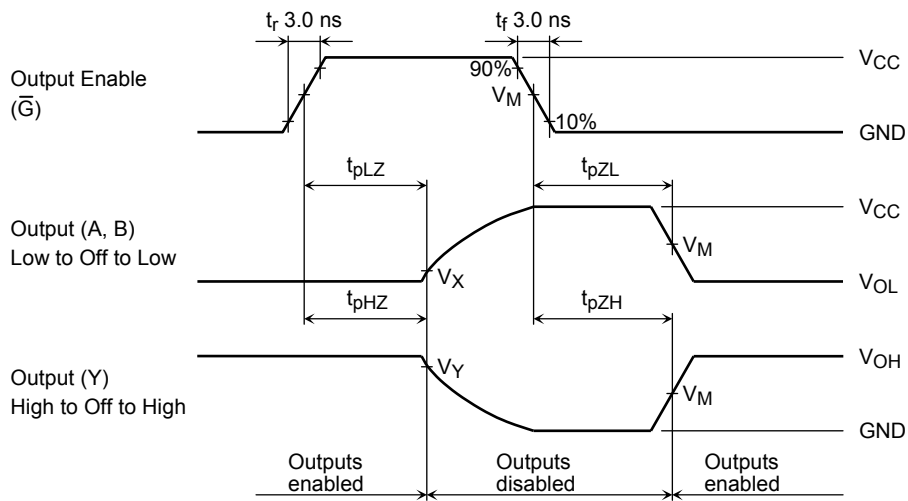
Characteristics	Switch
tpLH, tpHL	Open
tpLZ, tpZL	VCC x 2
tpHZ, tpZH	GND

**Figure1 tpLH, tpHL**

**AC Waveforms**



**Figure2  $t_{pLH}$ ,  $t_{pHL}$**



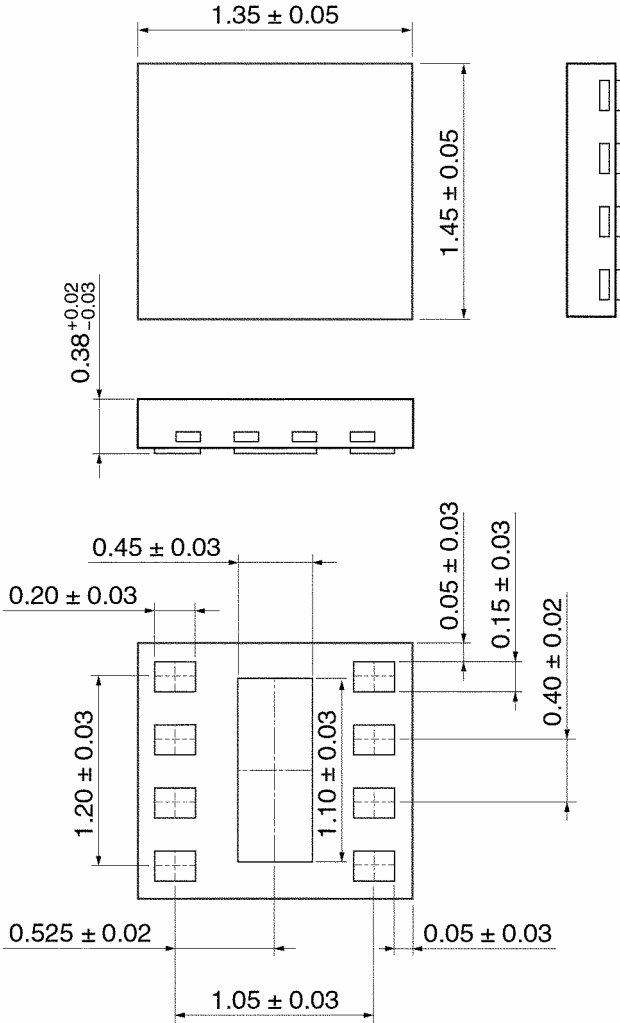
**Figure3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$**

UNIT	$V_{CC}$					
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	$1.8 \pm 0.15 \text{ V}$	$1.5 \pm 0.1 \text{ V}$	$1.2 \pm 0.1 \text{ V}$	$0.9 \text{ V}$
$V_M$	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$
$V_X$	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.1 \text{ V}$	$V_{OL} + 0.1 \text{ V}$	$V_{OL} + 0.1 \text{ V}$
$V_Y$	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.1 \text{ V}$	$V_{OH} - 0.1 \text{ V}$	$V_{OH} - 0.1 \text{ V}$

Package Dimensions

CSON8-P-0.4

Unit: mm



Weight : 0.002 g (Typ.)

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20070701-EN GENERAL

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